

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): David M. Fried et al.

Examiner: Ginette Peralta

Serial No: 09/683,328

Art Unit: 2814

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Docket: BUR920010171US1 (15017)

For IMPLANTED ASYMMETRIC DOPED POLYSILICON GATE FinFET

Dated: January 8, 2003_

TECHNOLOGY CENTER 2800

CEIVEU

Assistant Commissioner for Patents United States Patent and Trademark Office Washington, D.C. 20231

RESPONSE UNDER 37 C.F.R. §1.111 AND §1.143

Sir:

In response to the Office Action dated December 16, 2002, applicants provisionally elect, without traverse, the subject matter of Group II, i.e., Claims 12-28, for continued prosecution in the above-identified patent application.

REMARKS

Favorable consideration and allowance of the claims of the present application

CERTIFICATE OF MAILING UNDER 37 C.F.R. §1.8(a)

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Assistant Commissioner for Patents, Washington, D.C. 20231, on January 8, 2003.

Dated: January 8, 2003

Michelle Mustafa